



Dual N-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)			
20	0.280 at V _{GS} = 4.5 V	1.28			
	0.360 at V _{GS} = 2.5 V	1.13			
	0.450 at V _{GS} = 1.8 V	1.0			

FEATURES

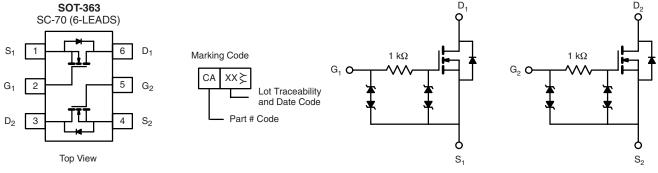
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFETs: 1.8 V Rated
- ESD Protected: 2000 V
- Thermally Enhanced SC-70 Package
- Compliant to RoHS Directive 2002/95/EC



ROHS
COMPLIANT
HALOGEN
FREE

APPLICATIONS

- Load Switching
- PA Switch
- · Level Switch



Ordering Information: Si1912EDH-T1-E3 (Lead (Pb)-free)

Si1912EDH-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATIN	GS $T_A = 25 ^{\circ}C$,	unless other	wise noted		
Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	20		V
Gate-Source Voltage		V_{GS}	± 12		ľ
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	I _D	1.28	1.13	A
	T _A = 85 °C		0.92	0.81	
Pulsed Drain Current		I _{DM}	4		A
Continuous Diode-Current (Diode Conduction) ^a		I _S	0.61	0.48	
Maximum Power Dissipation ^a	T _A = 25 °C	P _D	0.74	0.57	W
	T _A = 85 °C	1 ^{FD}	0.38	0.30	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^a	t ≤ 5 s	- R _{thJA}	130	170	°C/W
	Steady State		170	220	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	80	100	

Notes:

a. Surface mounted on 1" x 1" FR4 board.

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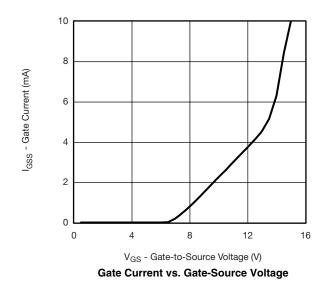
SPECIFICATIONS T _J = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Conditions Mir		Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 100 \mu A$	0.45			V		
Gate-Body Leakage		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$			± 1	μΑ		
	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			± 10	mA		
Zero Gate Voltage Drain Current		V _{DS} = 16 V, V _{GS} = 0 V			1			
	I _{DSS}	V_{DS} = 16 V, V_{GS} = 0 V, T_J = 85 °C			5	μΑ		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	2			Α		
	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 1.13 A		0.220	0.280	Ω		
Drain-Source On-State Resistance ^a		V _{GS} = 2.5 V, I _D = 0.99 A		0.281	0.360			
		V _{GS} = 1.8 V, I _D = 0.2 A		0.344	0.450			
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 1.13 A		2.6		S		
Diode Forward Voltage ^a	V _{SD}	I _S = 0.48 A, V _{GS} = 0 V		0.8	1.2	V		
Dynamic ^b	·							
Total Gate Charge	Qg			0.65	1	nC		
Gate-Source Charge	Q _{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 1.13 \text{ A}$		0.2				
Gate-Drain Charge	Q _{gd}			0.23				
Turn-On Delay Time	t _{d(on)}			45	70	- ns		
Rise Time	t _r	$V_{DD} = 10 \text{ V}, R_L = 20 \Omega$ $I_D \cong 0.5 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 6 \Omega$		85	130			
Turn-Off Delay Time	t _{d(off)}			350	530			
Fall Time	t _f			210	320			

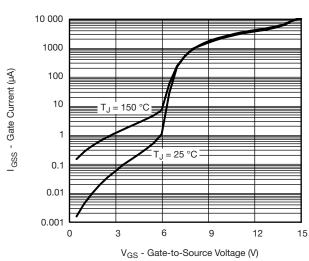
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. Guaranteed by design, not subject to production testing.

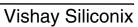
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



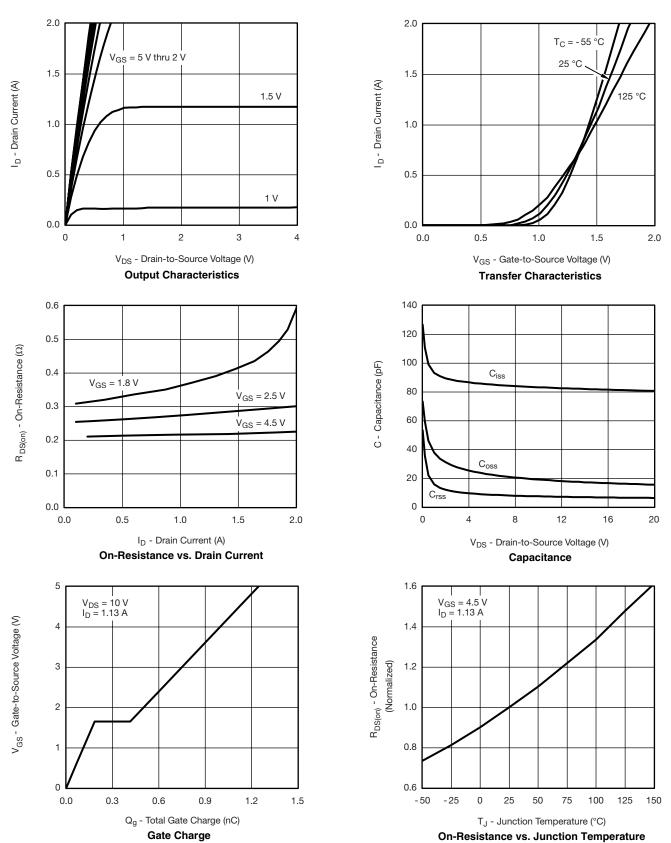








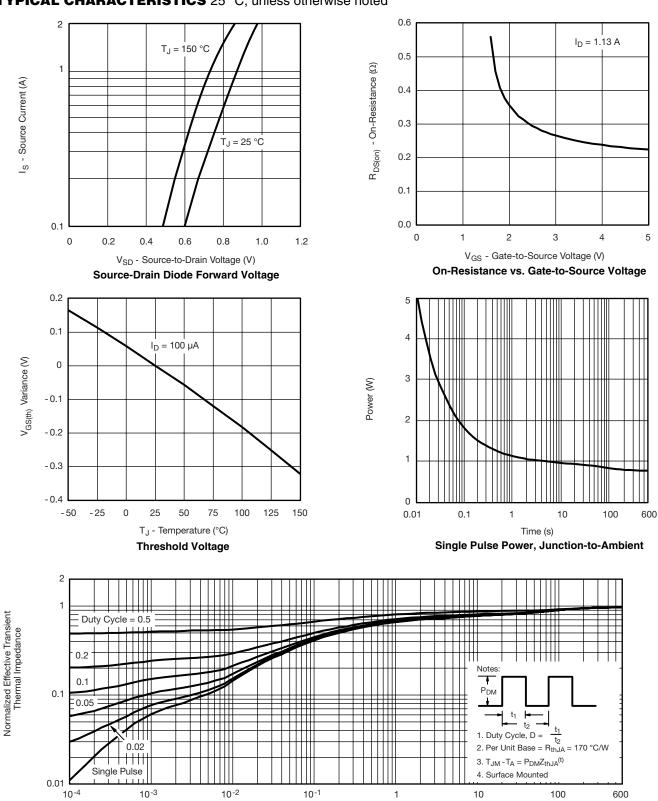
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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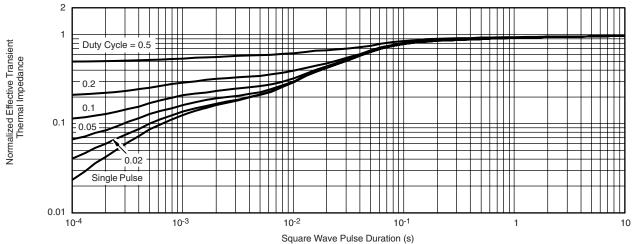
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg271408.



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